NSN 5961-00-908-1997

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-908-1997 **Inclosure Material:** Glass and metal **Overall Length:** 0.800 inches **Terminal Length:** 1.000 inches **Overall Diameter:** 0.400 inches **Function For Which Designed:** Voltage variable capacitor **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 30.0 reverse voltage, peak **Power Rating Per Characteristic:** 0.5 watts small-signal input power, common-collector preset **Capacitance Rating In Picofarads:** 470.0 **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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